

All laser diodes are extremely electrostatic sensitive; see page 1244 for our selection of antistatic products.



## $\lambda = 660 \text{ nm}$ , $P = 120 \text{ mW}$ , Single Mode Hitachi HL6545MG

### Maximum Ratings ( $T_c = 25^\circ\text{C}$ )

CHARACTERISTIC	SYMBOL	RATING
Optical Output Power (CW)	$P_o$	130 mW
Pulse Optical Output Power	$P_o(\text{pulse})$	300 mW*
LD Reverse Voltage	$V_{R(\text{LD})}$	2 V
CW Operation Case Temperature	$T_c$	-10 to +75 °C
Pulse Operation Case Temperature	$T_{(\text{pulse})}$	-10 to +75 °C
Storage Temperature	$T_{\text{stg}}$	-40 to +85 °C

\*Note: Pulse width = 30 ns, duty = 35%

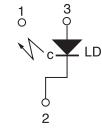
### Characteristics ( $T_c = 25^\circ\text{C}$ , $P = 120 \text{ mW}$ )

CHARACTERISTIC	SYMBOL	MIN	TYP.	MAX
Threshold Current	$I_{\text{th}}$	—	55 mA	75 mA
Operation Current	$I_{\text{op}}$	—	170 mA	210 mA
Operation Voltage	$V_{\text{op}}$	2.45 V	2.6 V	3.0 V
Lasing Wavelength	$\lambda_p$	652 nm	660 nm	664 nm
Beam Divergence (FWHM)	$\theta_{/\!/}$	7.5°	10°	12°
	$\theta_{\perp}$	15°	17°	19°
Astigmatism ( $P_o = 5 \text{ mW}$ )	$A_s$	—	1 μm	—

Note: All data is presented as typical unless otherwise specified.

#### Pin Description

- 1 no connection
- 2 laser cathode
- 3 laser anode



**NEW**  
product

- Ø5.6 mm Package

- 1 μm Astigmatism @ 5 mW

- 170 mA (Typ.) Operating Current

ITEM#	£* 1-5 PCS	€* 1-5 PCS	RMB* 1-5 PCS
HL6545MG	£ 50.03	€ 64,53	¥ 611.90

\*For quantities over 5 pieces, please call a local office for pricing.

ITEM#	PRICE 1-5 PCS	PRICE 6-10 PCS	PRICE 11-20 PCS	DESCRIPTION
HL6545MG	\$ 72.50	\$ 61.63	\$ 50.75	Hitachi 660 nm, 120 mW

## $\lambda = 670 \text{ nm}$ , $P = 5 \text{ mW}$ , Single Mode Hitachi HL6724MG

### Maximum Ratings ( $T_c = 25^\circ\text{C}$ )

CHARACTERISTIC	SYMBOL	RATING
Optical Output Power (CW)	$P_o$	5 mW
Optical Output Power (Pulse)	$P_o$	6 mW*
LD Reverse Voltage	$V_{R(\text{LD})}$	2 V
PD Reverse Voltage	$V_{R(\text{PD})}$	30 V
Operation Case Temperature	$T_c$	-10 to 50 °C
Storage Temperature	$T_{\text{stg}}$	-40 to 85 °C

\*Note: Pulse width ≤ 1 μs, duty ≤ 50%

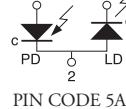
### Characteristics ( $T_c = 25^\circ\text{C}$ , $P = 5 \text{ mW}$ )

CHARACTERISTIC	SYMBOL	MIN	TYP.	MAX
Threshold Current	$I_{\text{th}}$	—	25 mA	35 mA
Operation Current	$I_{\text{op}}$	—	35 mA	50 mA
Operation Voltage	$V_{\text{op}}$	—	—	2.7 V
Lasing Wavelength	$\lambda_p$	660 nm	670 nm	680 nm
Beam Divergence (FWHM)	$\theta_{/\!/}$	5°	8°	11°
	$\theta_{\perp}$	22°	30°	40°
Monitor Current	$I_m$	0.4 mA	0.9 mA	2 mA

Note: All data is presented as typical unless otherwise specified.

#### Pin Description

- 1 monitor diode anode
- 2 common case
- 3 laser cathode



- Ø5.6 mm Package
- AlGaInP Index-Guided Laser Diode With a Multi-Quantum Well (MQW) Structure
- Pulsed Optical Power of 6 mW with a 50% Duty Cycle and a Maximum Pulse Width of 1 μs @ 5 mW
- 5 μm Astigmatism @ 5 mW

ITEM#	£* 1-5 PCS	€* 1-5 PCS	RMB* 1-5 PCS
HL6724MG	£ 15.77	€ 20,34	¥ 192.86

\*For quantities over 5 pieces, please call a local office for pricing.

ITEM#	PRICE 1-5 PCS	PRICE 6-10 PCS	PRICE 11-20 PCS	DESCRIPTION
HL6724MG	\$ 22.85	\$ 21.71	\$ 19.43	Hitachi 670 nm, 5 mW

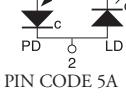
## $\lambda = 670 \text{ nm}$ , $P = 5 \text{ mW}$ , Single Mode Sanyo DL3149-057

### Absolute Maximum Ratings ( $T_c = 25^\circ\text{C}$ )

CHARACTERISTIC	SYMBOL	RATING
Optical Output Power (CW)	$P_o$	7 mW
LD Reverse Voltage	$V_{R(\text{LD})}$	2 V
PD Reverse Voltage	$V_{R(\text{PD})}$	30 V
Operation Case Temperature	$T_c$	-10 to 60 °C
Storage Temperature	$T_{\text{stg}}$	-40 to 85 °C

#### Pin Description

- 1 laser cathode
- 2 common case
- 3 monitor diode anode



- Ø5.6 mm Package
- AlGaInP Index-Guided MQW Structure
- 8 μm Astigmatism @ 7 mW
- High Operating Temperature of 5 mW at 60 °C

ITEM#	£* 1-5 PCS	€* 1-5 PCS	RMB* 1-5 PCS
DL3149-057	£ 10.56	€ 13,62	¥ 129.14

\*For quantities over 5 pieces, please call a local office for pricing.

ITEM#	PRICE 1-5 PCS	PRICE 6-10 PCS	PRICE 11-20 PCS	DESCRIPTION
DL3149-057	\$ 15.30	\$ 13.47	\$ 10.26	Sanyo 670 nm, 5 mW